

Tandem 600V HYPERFAST BOOST DIODE

MAJOR PRODUCTS CHARACTERISTICS

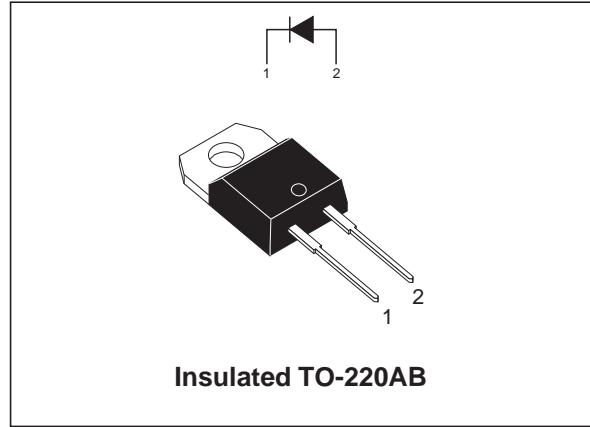
$I_{F(AV)}$	8 A
V_{RRM}	600 V
$T_j(\text{max})$	150 °C
$V_F(\text{max})$	2.4 V
$I_{RM}(\text{typ.})$	4 A
$t_{rr}(\text{typ.})$	13 ns

FEATURES AND BENEFITS

- ESPECIALLY SUITED AS BOOST DIODE IN CONTINUOUS MODE POWER FACTOR CORRECTORS AND HARD SWITCHING CONDITIONS
- DESIGNED FOR HIGH DI/DT OPERATION. HYPERFAST RECOVERY CURRENT TO COMPETE WITH SIC DEVICES. ALLOWS DOWNSIZING OF MOSFET AND HEATSINKS
- INTERNAL CERAMIC INSULATED DEVICES WITH EQUAL THERMAL CONDITIONS FOR BOTH 300V DIODES
- INSULATION (2500VRMS) ALLOWS PLACEMENT ON SAME HEATSINK AS MOSFET AND FLEXIBLE HEATSINKING ON COMMON OR SEPARATE HEATSINK
- STATIC AND DYNAMIC EQUILIBRIUM OF INTERNAL DIODES ARE WARRANTED BY DESIGN
- PACKAGE CAPACITANCE: $C=7\text{pF}$

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	600	V
$I_{F(\text{RMS})}$	RMS forward current	14	A
I_{FSM}	Surge non repetitive forward current	80	A
I_{peak}	Peak current waveform $\text{tp} = 10 \text{ ms sinusoidal}$	17	A
T_{stg}	Storage temperature range	-65 +150	°C
T_j	Maximum operating junction temperature	+ 150	°C



Insulated TO-220AB

DESCRIPTION

The TURBOSWITCH "H" is an ultra high performance diode composed of two 300V dice in series. TURBOSWITCH "H" family drastically cuts losses in the associated MOSFET when run at high dI_F/dt .

STTH806DTI

THERMAL AND POWER DATA

Symbol	Parameter	Test conditions	Value	Unit
$R_{th(j-c)}$	Junction to case thermal resistance		2.6	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests Conditions		Min.	Typ.	Max.	Unit
I_R^*	Reverse leakage current	$V_R = V_{RRM}$	$T_j = 25^\circ C$			10	μA
			$T_j = 125^\circ C$		15	100	
V_F^{**}	Forward voltage drop	$I_F = 8 A$	$T_j = 25^\circ C$			3.6	V
			$T_j = 150^\circ C$		1.95	2.4	

Pulse test : * $t_p = 100 \text{ ms}, \delta < 2\%$

** $t_p = 380 \mu\text{s}, \delta < 2\%$

To evaluate the maximum conduction losses use the following equation :
 $P = 1.7 \times I_{F(AV)} + 0.087 I_F^2(\text{RMS})$

RECOVERY CHARACTERISTICS

Symbol	Parameter	Tests Conditions		Min.	Typ.	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = 0.5 A \quad I_{rr} = 0.25 A$ $I_R = 1 A$	$T_j = 25^\circ C$		13		ns
						30	
I_{RM}	Reverse recovery current	$V_R = 400 V \quad I_F = 8 A$ $dI_F/dt = -200 A/\mu s$	$T_j = 125^\circ C$		4	5.5	A
S	Reverse recovery softness factor				0.4		-
Q_{rr}	Reverse recovery charges				50		nC

TURN-ON SWITCHING CHARACTERISTICS

Symbol	Parameter	Tests Conditions		Min.	Typ.	Max.	Unit
t_{fr}	Forward recovery time	$I_F = 8 A \quad dI_F/dt = 100 A/\mu s$, $V_{FR} = 1.1 \times V_{Fmax}$	$T_j = 25^\circ C$			200	ns
V_{FP}	Forward recovery voltage	$I_F = 8 A \quad dI_F/dt = 100 A/\mu s$	$T_j = 25^\circ C$			7	V

Fig. 1: Conduction losses versus average current.

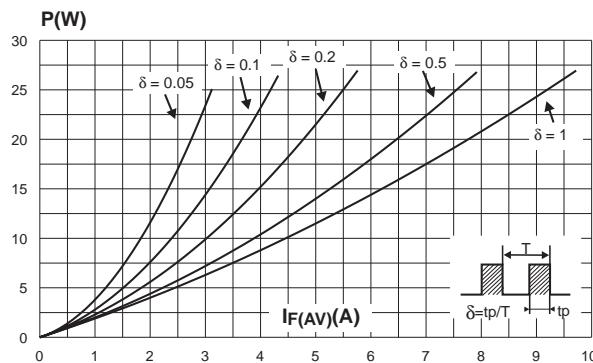


Fig. 2: Forward voltage drop versus forward current.

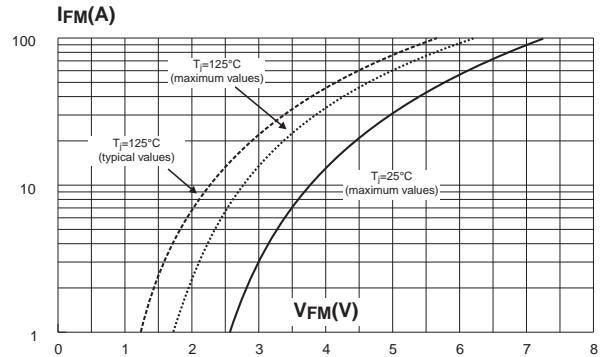


Fig. 3: Relative variation of thermal impedance junction to case versus pulse duration.

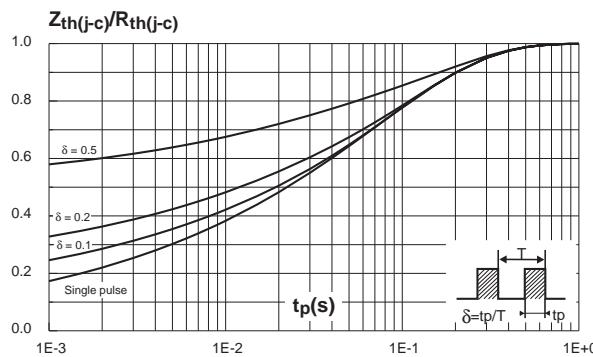


Fig. 4: Peak reverse recovery current versus dI_F/dt (typical values).

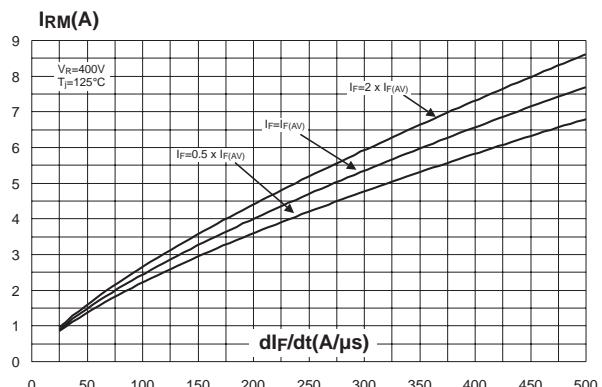


Fig. 5: Reverse recovery time versus dI_F/dt (typical values).

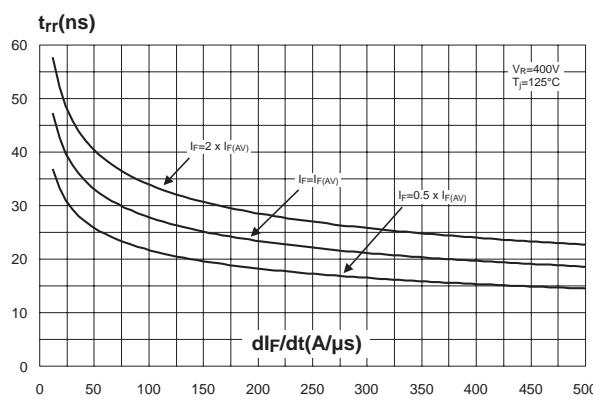
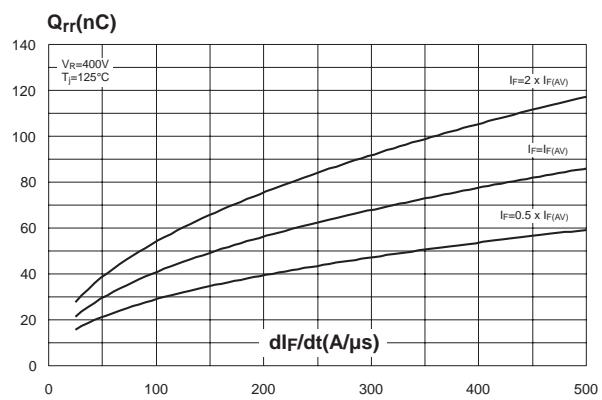


Fig. 6: Reverse charges versus dI_F/dt (typical values).



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Fig. 7: Softness factor versus dI_F/dt (typical values).

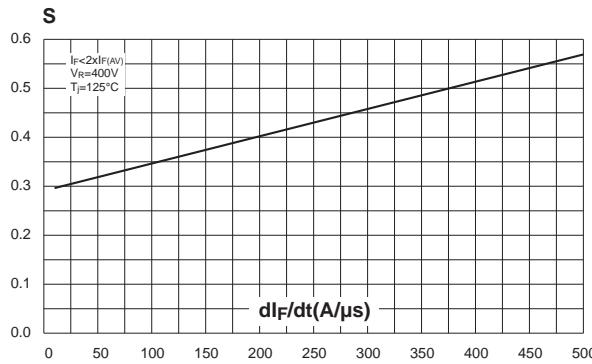


Fig. 8: Relative variation of dynamic parameters versus junction temperature (reference: $T_j = 125^\circ C$).

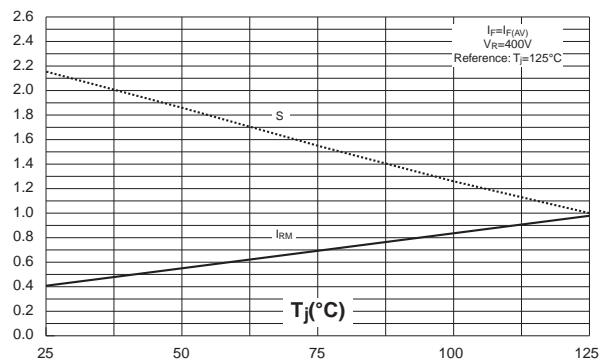


Fig. 9: Transient peak forward voltage versus dI_F/dt (typical values).

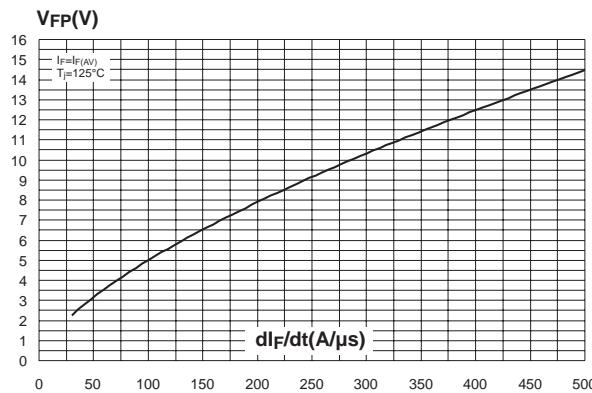
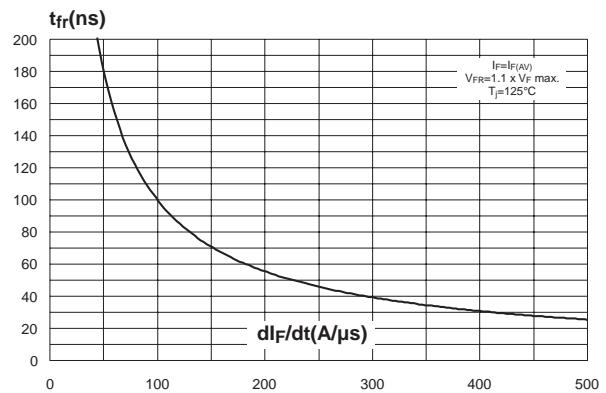
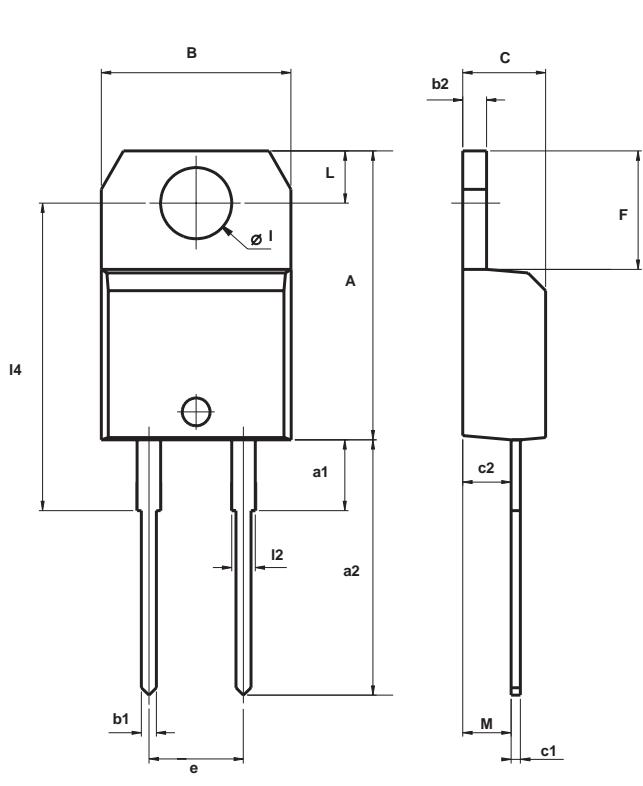


Fig. 10: Forward recovery time versus dI_F/dt (typical values).



PACKAGE MECHANICAL DATA
TO-220AC



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	4.80		5.40	0.189		0.212
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
M		2.60			0.102	

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH806DTI	STTH806DTI	TO-220AC	2.3 g.	50	Tube

- Cooling method: C
- Recommended torque value: 0.8 N.m.
- Maximum torque value: 1 N.m.
- Epoxy meets UL94, V0

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